



DW05D5UC-B-E ESD Protection Diode

Feature

- Bi-directional ESD protection of one line
- 60Watts peak pulse power ($t_p=8/20\mu s$)
- Working voltage: 5V
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance ($C_j=0.35pF$ typ.)
- IEC 61000-4-2 $\pm 15kV$ Contact $\pm 20kV$ Air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 3A (8/20 μs)

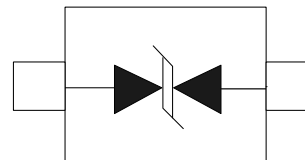
Application

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Mechanical Data

- Package: SOD-523
- Molding compound flammability rating: UL 94V-0
- RoHS/WEEE Compliant

Schematic & PIN Configuration



Ordering Information

Part Number	Package	Marking	QTY per Reel	Reel Size
DW05D5UC-B-E	SOD-523		5000 pcs	7 inches



Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Units
Peak Pulse Power ($t_p=8/20\mu\text{s}$)	P_{PP}	60	Watts
Peak Pulse Current ($t_p=8/20\mu\text{s}$) (note1)	I_{pp}	3	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	± 20 ± 15	kV
Lead Soldering Temperature	T_L	260 (10seconds)	$^{\circ}\text{C}$
Junction Temperature	T_J	-55 to + 125	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55 to + 125	$^{\circ}\text{C}$

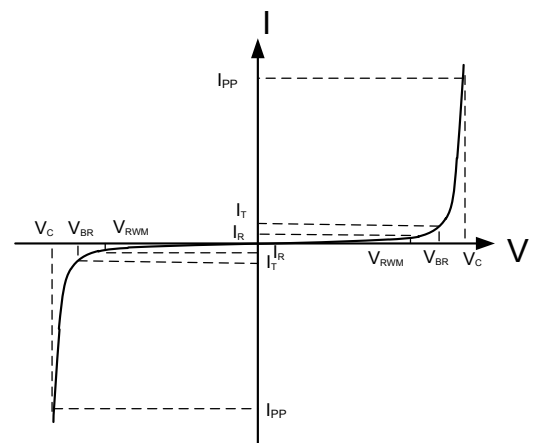
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V_{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	6.0	8.0		V
Reverse Leakage Current	I_R	$V_{RWM}=5\text{V}, T=25^{\circ}\text{C}$		0.1	0.5	μA
Peak Pulse Current	I_{PP}	$t_p=8/20\mu\text{s}$			3	A
Clamping Voltage	V_C	$I_{PP}=3\text{A}, t_p=8/20\mu\text{s}$			20	V
Junction Capacitance	C_j	$V_R=0\text{V}, f=1\text{MHz}$		0.35		pF

Electrical Parameters

Symbol	Parameter
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Working Peak Reverse Voltage
I_R	Maximum Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current

Note: 8/20 μs pulse waveform.





Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

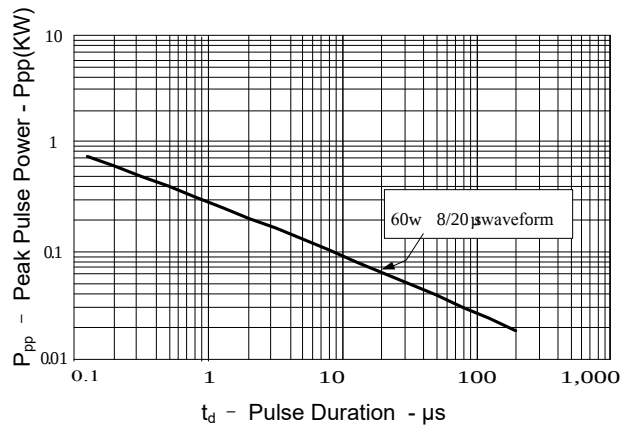


Figure 2: Power Derating Curve

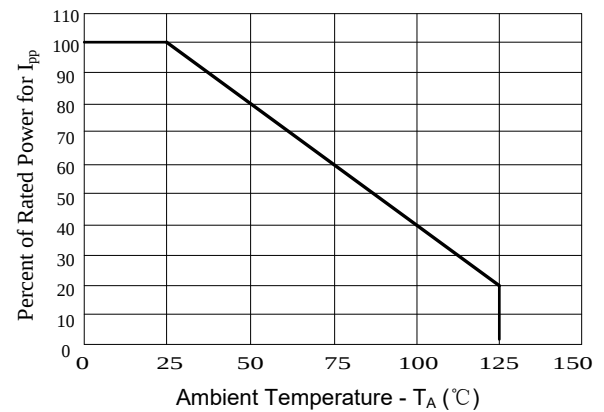


Figure3: Pulse Waveform

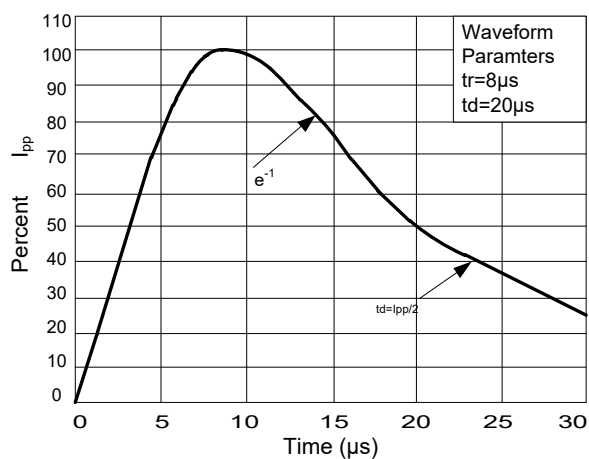
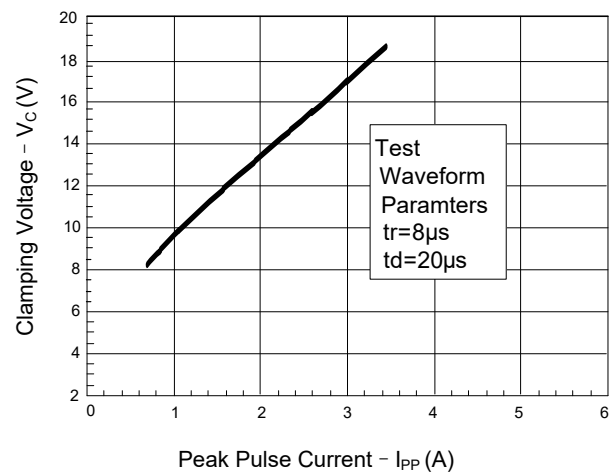
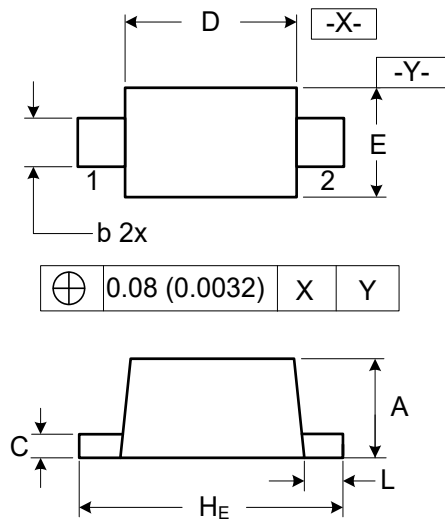


Figure 4: Clamping Voltage vs. I_{pp}





SOD-523 Outline Drawing



DIMENSIONS

SYMBOL	MILLIMETER		INCHES	
	MIN	MAX	MIN	MAX
A	0.50	0.70	0.020	0.028
b	0.25	0.35	0.010	0.014
C	0.07	0.20	0.0028	0.0079
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
H _E	1.50	1.70	0.059	0.067
L	0.15	0.25	0.006	0.010